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High magnetic field corrections to resistance thermometers at low temperatures

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We present a reliable method to account for the magnetoresistance of resistance sensors which are used as thermometers in many low temperature (T ≤ 20 K) experiments carried out in high magnetic fields (to 31 T). To apply the method, a set of isothermal magnetoresistance data, and a zero magnetic field temperature calibration are first necessary. A simple algorithm, which uses this data set, can then be applied to compute the temperature from the measured resistance at any field. The method is particularly useful for temperature dependent measurements at fixed field, or where, in cases where the temperature may change unpredictably during a change in magnetic field. We apply this method to the treatment of data in two separate experiments with the two different thermometers, RuO2 (below 1 K) and Cernox (above 1 K) sensors, respectively. © 1999 American Institute of Physics. [S0034-6748(99)02404-1]

I. INTRODUCTION

Resistance sensors such as RuO2 (Refs. 1–7) and Cernox (Refs. 8–11) have been widely used as thermometers at low temperatures due to their small size, simple instrumentation, and their relatively small magnetoresistance. However, with the expanding range of available magnetic fields and temperatures at high magnetic facilities worldwide, temperature errors due to magnetoresistance effects may occur in certain limits, if based on the zero field calibration. Specifically, at low temperatures disorder effects (weak localization12) may produce a large change in the resistance in the low field region. And at higher temperatures, where the sensitivity can be orders of magnitude less, small changes due to magnetoresistance become quite significant. Typically, the errors can be of the order of 10%–20% of the actual temperature in fields in the range 10–30 T. There are several alternatives to adjusting for these high field magnetoresistance effects, as recently described by Goodrich et al.13 for RuO2 in the 0.03–0.6 K range up to 32 T, and by Brandt, Liu, and Rubin14 for Cernox sensors in the range 2–286 K also up to 32 T as applied to calibrated commercial sensors. In this article we show how, with a simple calibration procedure, one can obtain reliable values of the temperature from resistive sensors, based only on the value of the resistance and magnetic field for any specific data point. The method is general, and in principle can be applied to any experimental parameter which varies with temperature and magnetic field. Single valuedness of the parameter versus field and temperature is preferred, but not required. We provide two examples where the method has been successfully implemented.

II. PRINCIPLE OF METHOD

A. Calibration

It is necessary to first establish a calibration curve of resistance versus temperature at zero field, as shown for instance in Fig. 1(a) for the RuO2 sensor14 used in this article. This calibration may be obtained from the manufacturer, or done by the experimenter at zero magnetic field by standard primary or secondary thermometry methods.15 We have found that a polynomial expansion of the log of the temperature in terms of the log of the resistance provides an excellent fit to the resistive sensors we have studied. The second, crucial step is to obtain a set of (ideally) isothermal curves16 of the resistance of the sensor versus magnetic field. We have used polynomial fits in our application, with as many terms as are needed to describe the data. This is to be distinguished from approaches where specific functions which describe physical models are used. In Fig. 1(b) we show the magnetoresistance data set for the RuO2 sensor. The extent to which the temperature remains constant depends on the details of the experiment. In the cases studied in this article (see Sec. III) the magnetic field was swept very slowly, the thermometers were immersed in the cryogenic coolant, and the value of the resistance at the beginning and the end of the magnetic field sweep were nearly identical. In experimental situations where this is not possible, one may always use a transfer standard such as a capacitive thermometer11 to electronically regulate the temperature during the magnetic field sweep.

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dependent resistance, for selected isotherms, of the RuO$_2$ resistance thermometer. A sufficient term to represent nonlinearity in the field dependence of Fig. 1 is obtained from Fig. 1. To accomplish this the isotherms are represented as a polynomial in magnetic field $B$. Parameterization and algorithm

The key feature of our method is to compute, based on a single value of the resistance at a particular field, the corresponding value of resistance at zero field. From this the temperature may be easily computed from the zero field calibration. Although the parameters in the computation depend on isothermal data initially, the resulting method relies only on the value of the resistance and the magnetic field at a single point, regardless of the details of any subsequent experiments. We demonstrate the method based on the RuO$_2$ data from Fig. 1. To accomplish this the isotherms (indexed by $i$) must first be accurately parameterized (i.e., with a sufficient term to represent nonlinearity in the field dependence). We therefore consider the relations

\[ R_i(B) = \sum_n b_n[R_0(T_i)]B^n \]  

and

\[ b_n[R_0(T_i)] = \sum_m [d_{nm}R_0(T_i)^m]. \]  

In the above expressions we note that temperature is implicit in the zero field resistance according to $R_0(T_i)$. The notation in Eqs. (1) and (2) is further described as follows.

(a) Equation (1) expresses the resistance on an isotherm $T_i$ as a polynomial in magnetic field. A fifth order polynomial in magnetic field ($B$) is generally sufficient. Referring to Fig. 2, we fit each of the isotherms to Eq. (1), thereby generating a set of coefficients $b_n[R_0(T_i)]$ for each isotherm.

(b) Equation (2) states that the coefficients of the polynomial expansion in Eq. (1) are themselves explicit functions of $R_0(T)$ (implicit functions of $T$). We may therefore expand each coefficient $b_n[R_0(T_i)]$ in terms of a polynomial in $R_0(T)$ to obtain the final set of coefficients $d_{nm}$. The first coefficient in Eq. (1) for each isotherm, namely $b_0[R_0(T_i)]$, is equal to $R_0(T_i)$, i.e., $d_{00} = 1$, and $d_{0n} = 0$ for $n \neq 0$. The result of the procedure for determining the coefficients $d_{nm}$ is illustrated in Fig. 2. Here a sixth order polynomial in $R_0(T)$ is sufficient to accurately determine the $d_{nm}$ coefficients. We note that at low temperatures the resistance, and also the magnetoresistance, changes significantly for small changes in temperature (of the order of tens of millidegrees Kelvin). Hence a finer mesh of data between 80 and 30 mK would be needed to reduce the tendency of the polynomial to oscillate in the low temperature tail. Nevertheless Fig. 2 shows a detailed balance of odd and even terms of $b_n$ and the solution of Eq. (3) is well behaved, as the results of Fig. 3 will show.

Once all coefficients are determined, Eq. (1) may be expressed as more general function of $B$ and $T$:

\[ R(B) = \sum_{n,m} d_{nm}R_0(T)^mB^n. \]  

Equation (3) may then be solved for $R_0(T)$ by standard root search methods, given $R(B)$ and $B$ at any data point. With the value of $R_0(T)$ which corresponds to $R(B)$ determined, the temperature may be obtained from the original calibration relation. Examples of the program code and coefficients are available for application on the internet. In the event that the $R-T-B$ relationship for a particular thermometer is double valued somewhere, the root search program may be modified to place the initial guess for $R_0(T)$ in closer proximity to the solution.

![Figure 1](image1.png)

![Figure 2](image2.png)
III. APPLICATION TO EXPERIMENT

We treat two experimental cases. (1) The first is an experiment on a 200 layer GaAs/AlGaAs structure. Here the calibrated 1000 Ω RuO$_2$ sensor (Fig. 1) in the mixing chamber of an Oxford Instruments top-loading dilution refrigerator was used to monitor the temperature during field sweeps to determine the magnetoresistance $R_{xx}$ in a standard transport measurement. For each temperature at which a field sweep was made, a heater was used to warm the mixing chamber above the base temperature of about 0.03 K. About 1 h was needed for the system to come into thermal equilibrium after each new heater setting. The maximum heat applied was 6 mW at 0.7 K. To avoid heating due to eddy current effects, the field was swept at 0.032 T/min, and thermal drift was always checked by comparing the value of the RuO$_2$ sensor at the beginning and end of each field cycle—typically between 0 and 17.5 T. In Fig. 3(a) we show a trace of $R_{xx}$ along with the temperature sensor for a field cycle at 0.03 K. Of interest in this particular experiment was the temperature dependence of the $R_{xx}$ minimum at the $v=2$ filling factor which occurs at about 8.6 T. This may be accomplished in two ways—either by systematic isothermal field sweeps to pick off the $R_{xx}$ minimum, or more conveniently, by fixing the field at the minimum, and changing the temperature. In the latter case however, there will be considerable error in the temperature if the magnetoresistance is not accounted for, since it too is temperature dependent. In Fig. 3(b) a comparison of the two ways of data acquisition are shown. The discrete points are the field sweep data where $R_{xx}$ is picked off of each isothermal magnetoresistance curve, and the continuous data are $R_{xx}$ versus temperature, as determined from our method which accounts for the magnetoresistance of the thermometer. Also shown is the same data, without the magnetoresistance correction. Although such errors are only about 10% in magnitude, they may seriously compromise data analysis where it is necessary to distinguish, say, between activated, power law, or variable range hopping models for the transport data.

(2) The second example used a Cernox sensor. Here the temperature dependence of the resistance of an organic conductor (BEDT-TTF)$_2$KHg(SCN)$_4$ has been investigated for different fixed magnetic fields orientation. The magnetic field dependence of the resistance for isotherms of the Cernox sensor. Where taken, up and down field sweeps overlap very well. Solid lines—fourth order polynomial fits in $B$ to the data. $T_{meas}$ refers to the apparent temperature at high field (30 T) based on the zero field calibration.
IV. UNCERTAINTIES IN THE PROCEDURE

The present work uses a zero field calibration of a sensor (either calibrated by a researcher, or by a manufacturer) as the reference point for the high field calibration procedure. Hence the accuracy to which the final, absolute temperature value at high fields is accurate depends on the precision to which the calibration has been carried out, and the care the experimenter exercises in properly measuring the resistance (i.e., self-heating effects, etc.). The ultimate accuracy further depends on the degree to which the field sweeps in the field calibration are truly isothermal, and how faithfully the parameterization represents the magnetoresistance. In the work presented here we have focused on the process of going from the zero field calibration to the high field calibration. Hence we only consider the uncertainties due to nonisothermal conditions and imprecise parameterizations for the field calibration. First we have shown in the isothermal data the errors in temperature which will result if the magnetoresistance is not accounted for [Figs. 1(b) and 4(b)]. Second, to indicate in a practical manner how the zero field and high field calibrations correspond, we have presented two experimental examples where the procedure has been carried out. In the case of the low temperature example for the RuO$_2$ sensor [Fig. 3(b)], we may take 70 mK as a reference point. Here, without the field calibration, the error in temperature would be about 18 mK, i.e., the $R_{xx}$ value at 70 mK would appear at 52 mK, an error of about 25%. In the inset of Fig. 3(b), we note that ideally the discrete field sweep data should fall exactly on the continuous temperature sweep data. Again, taking the 70 mK point as reference, we see there is a shift of up to 5 mK between the two data sets, which results in an error of 7% for this point. Inspection of the full data set in Fig. 3(b) shows a similar uncertainty, some of which is attributable to the $R_{xx}$ measurement, but the field corrected scale is clearly superior to the zero field calibration in all cases. In the second experiment where a Cernox sensor was used, we may take the results of Fig. 5(b) to serve as a scale of the uncertainties. At low temperatures, if we assume the same base temperature is reached at the end of each sweep, then the maximum deviation is about 0.1 K from 0 to 30 T, or 5%. At the high temperature end, again if we assume the starting temperatures are the same, the maximum deviation is about 0.2 K from 0 to 30 T, or about 2%. Since the heating and cooling times were not always precisely the same, the actual uncertainties are less (we estimate 2.5% at 2 K and 1% at 12 K). Again, with no correction for the field dependence, we see by inspection of Figs. 4 and 5(a) that the errors would be as high as 14% at 2 K and 9% at 10 K.

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3. We use the term RuO$_2$ in this article for convenience. The composition of these sensors include Ru$_2$Bi$_2$O$_7$. See Ref. 13 and references therein.
6. Cernox is a brand name for zirconium oxy-nitride film sensors from Lake Shore Cryotronics, Inc. 575 McCorkle Blvd., Westerville OH 43082. The sensor used in this article was calibrated at zero field by the manufacturer. Lake Shore also is a vendor for calibrated RuO$_2$ sensors.
10. This sensor was installed and calibrated by the dilution refrigerator manufacturer, Oxford Instruments, Old Station Way, Eynsham, Witney, Oxon OX8 1TL, UK.
11. See for instance the recent review article by L. Rubin, Cryogenics 37, 341 (1997).
12. We use the term ‘‘isotherm’’ for convenience to describe field sweeps where the temperature did not drift significantly over the period of the data acquisition. Some drift and/or noise in the data are inevitable in many cases of high field experiments.
13. There are, in general dozens of polynomial terms, each of which must be computed many times to obtain a solution for $R_0(T)$. Again, this computation must be performed for perhaps thousands of data points from an experiment. However, current desk-top computers running at over 300 MHz can produce a corrected temperature scale in seconds or less.
14. Examples of the program are available through the NHMFL (Ref. 21) website, http://theory.magnet.fsu.edu/btt/btt.html. They are written for RuO$_2$ sensor ‘‘R4’’ in the NHMFL Millikelvin Facility top-loading dilution refrigerator. The application program is Igor Pro (WaveMetrics, Inc., P.O. Box 2088, Lake Oswego, OR 97035).
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